NSN 5961-01-625-6771

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-625-6771 **Inclosure Material:** Glass **Overall Length:** 0.744 inches **Overall Height:** 0.200 inches **Overall Width:** 0.645 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 drain to gate voltage and 70.0 drain to source voltage **Current Rating Per Characteristic:** 4.5 amperes drain current **Power Rating Per Characteristic:** 80.0 watts total device dissipation **Product Name:** Rf power Idmos transistor **Special Features:** 200 c maximum junction temp **Terminal Type And Quantity:** 4 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**